Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
Between 0.680 inches and 0.720 inches
Mounting Method:
Terminal
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, dc
Current Rating Per Characteristic:
100.00 nanoamperes forward current, average outside diameter
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
0.02
Special Features:
Hardness critical process; junctin pattern arrangement: pin
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Terminal Type And Quantity:
2 ribbon
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0